TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

## 2SC4667

# Ultra High Speed Switching Applications Computer, Counter Applications

• High transition frequency:  $f_T = 400 \text{ MHz}$  (typ.)

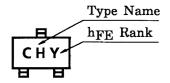
• Low saturation voltage:  $V_{CE (sat)} = 0.3 \text{ V (max)}$ 

• High speed switching time:  $t_{stg} = 15 \text{ ns (typ.)}$ 

#### **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	40	V
Collector-emitter voltage	$V_{CEO}$	15	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	IC	200	mA
Base current	ΙΒ	40	mA
Collector power dissipation	P <sub>C</sub>	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	−55 <b>~</b> 125	°C

#### Marking



1. BASE
2. EMITTER
3. COLLECTOR

JEDEC

JEITA

Unit: mm

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1.25±0.1

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2-2E1A

Weight: 0.006 g (typ.)

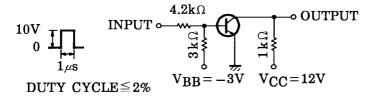
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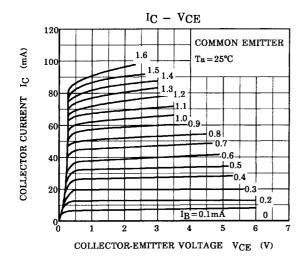
### Electrical Characteristics (Ta = 25°C)

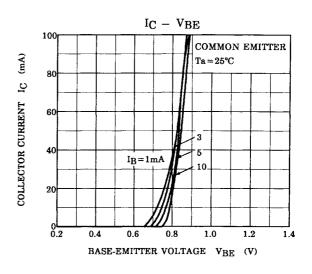
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = 40 \text{ V}, I_{E} = 0$	_	_	0.1	μА
Emitter cut-off cur	rent	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	0.1	μА
DC current gain		h <sub>FE (1)</sub> (Note 1)	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 10 mA	40	_	240	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 100 mA	20	_	_	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	$I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$	_	_	0.3	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	$I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$	_	_	1.0	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 10 mA	200	400	_	MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	4	6	pF
Switching time	Turn-on time	t <sub>on</sub>			70		
	Storage time	t <sub>stg</sub>	(Note 2)	_	15	_	ns
	Turn-off time	t <sub>off</sub>		_	30	_	

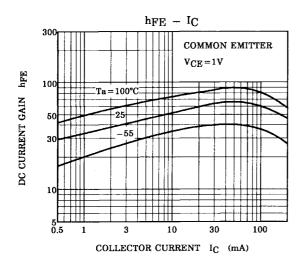
Note 1: hFE (1) classification R: 40~80, O: 70~140, Y: 120~240

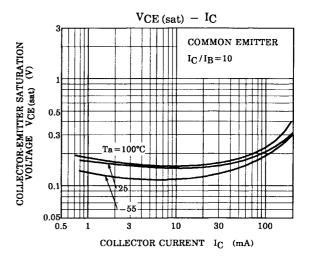
Note 2: Switching time test circuit

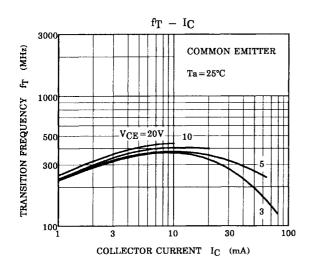


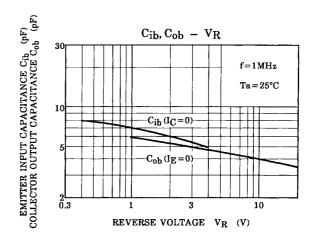


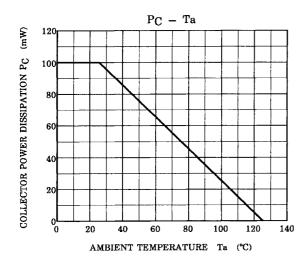












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